AP64501SP-EVM

40V, 5A, Low IQ, Synchronous DC/DC Buck Converter with Programmable Soft-Start Time

DESCRIPTION

The AP64501 is 5A, synchronous buck converter with a wide input voltage range of 3.8V to 40V. The device fully integrates a 45mΩ high-side power MOSFET and a 20mΩ low-side power MOSFET to provide high-efficiency step-down DC/DC conversion.

The AP64501 device is easily used by minimizing the external component count due to its adoption of peak current mode control.

The AP64501 design is optimized for Electromagnetic Interference (EMI) reduction. The converter features Frequency Spread Spectrum (FSS) with a switching frequency jitter of ±6%, which reduces EMI by not allowing emitted energy to stay in any one frequency for a significant period of time. It also has a proprietary gate driver scheme to resist switching node ringing without sacrificing MOSFET turn-on and turn-off times, which reduces high-frequency radiated EMI noise caused by MOSFET switching.

The device is available in a SO-8EP package.

FEATURES

- Wide Input Range: 3.8V to 40V
- 5A Continuous Output Current
- 0.8V ±1% Reference Voltage
- 25μA Ultralow Quiescent Current (Pulse Frequency Modulation)
- 570kHz Switching Frequency
- Programmable Soft-Start Time
- Proprietary Gate Driver Design for Best EMI Reduction
- Frequency Spread Spectrum (FSS) to Reduce EMI
- Low-Dropout (LDO) Mode
- Precision Enable Threshold to adjust UVLO
- Protection Circuitry
  - Undervoltage Lockout (UVLO)
  - Output Overvoltage Protection (OVP)
  - Cycle-by-Cycle Peak Current Limit
  - Thermal Shutdown
- Totally Lead-Free & Fully RoHS Compliant
- Halogen and Antimony Free. “Green” Device

APPLICATIONS

- 5V, 12V, and 24V Distributed Power Bus Supplies
- White Goods and Small Home Appliances
- Home Audio
- Network Systems
- Consumer Electronics
- Cordless Power Tools
- Optical Communication and Networking Systems
- General Purpose Point of Load

TYPICAL APPLICATIONS CIRCUIT

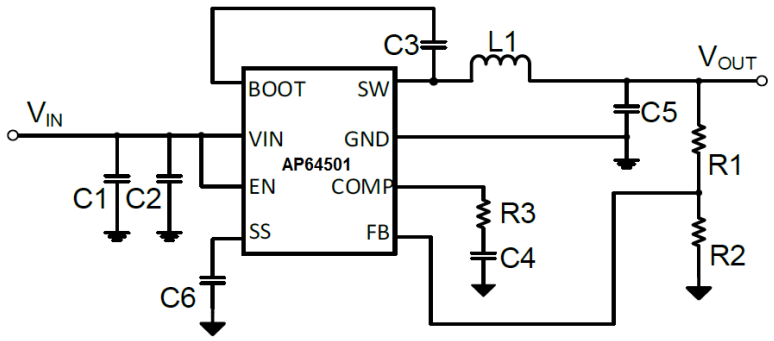


Figure 1. Typical Application Circuit

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Rating	Unit
VIN	Supply Pin Voltage	-0.3 to +42.0 (DC)	V
		-0.3 to +45.0 (400ms)	
V_{BST}	Bootstrap Pin Voltage	V_{SW} - 0.3 to V_{SW} + 6.0	V
V_{EN}	Enable/UVLO Pin Voltage	-0.3 to +42.0	V
V_{SS}	Soft-Start Pin Voltage	-0.3 to +6.0	V
V_{FB}	Feedback Voltage	-0.3V to +6.0	V
V_{COMP}	Compensation Pin Voltage	-0.3 to +6.0	V
V_{SW}	Switch Node Voltage	-0.3 to VIN + 0.3 (DC)	V
		-2.5 to VIN + 2.0 (20ns)	
T_J	Junction Temperature	+160	°C
T_L	Lead Temperature	+260	°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
VIN	Supply Voltage	3.8	40	V
VOUT	Output Voltage	0.8	39	V
T_A	Operating Ambient Temperature Range	-40	+85	°C
T_J	Operating Junction Temperature Range	-40	+125	°C

EVALUATION BOARD

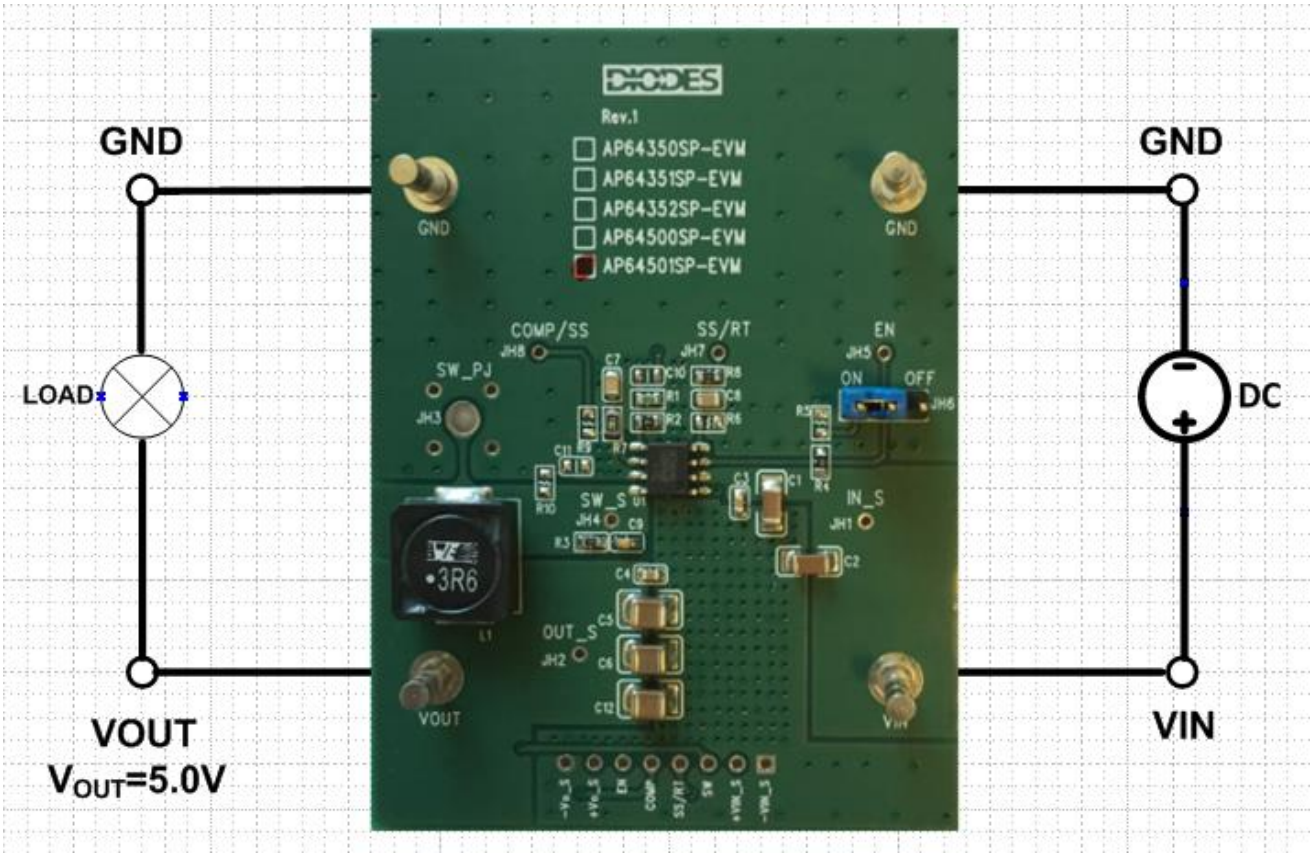


Figure 2. AP64501SP-EVM

QUICK START GUIDE

The AP64501SP-EVM has a simple layout and allows access to the appropriate signals through test points. To evaluate the performance of the AP64501SP, follow the procedure below:

1. Connect a power supply to the input terminals V_{IN} and GND. Set V_{IN} to 12V.
2. Connect the positive terminal of the electronic load to V_{OUT} and negative terminal to GND.
3. For Enable, place a jumper at JH6 to "ON" position to connect EN pin to V_{IN} through 100KΩ resistor to enable IC. Jump to "OFF" position to disable IC.
4. The evaluation board should now power up with a 5.0V output voltage.
5. Check for the proper output voltage of 5.0V (±1%) at the output terminals V_{OUT} and GND. Measurement can also be done with a multimeter with the positive and negative leads between V_{OUT} and GND.
6. Set the load to 5A through the electronic load. Check for the stable operation of the SW signal on the oscilloscope. Measure the switching frequency.

MEASUREMENT/PERFORMANCE GUIDELINES:

1) When measuring the output voltage ripple, maintain the shortest possible ground lengths on the oscilloscope probe. Long ground leads can erroneously inject high frequency noise into the measured ripple.

2) For efficiency measurements, connect an ammeter in series with the input supply to measure the input current. Connect an electronic load to the output for output current.

SETTING OUTPUT VOLTAGE:

Table 1 shows a list of recommended component selections for common output voltages.

VOUT	R1	R2	L1	R7	C7	C1, C2	C5, C6, C12
1.2V	11KΩ	22.1KΩ	1.5µH	3.74KΩ	2.7nF	2x10µF	3x22µF
1.5V	19.6KΩ	22.1KΩ	2.2µH	4.75KΩ	2.7nF	2x10µF	3x22µF
1.8V	27.4KΩ	22.1KΩ	2.2µH	5.62KΩ	2.7nF	2x10µF	3x22µF
2.5V	47.5KΩ	22.1KΩ	3.3µH	7.87KΩ	2.7nF	2x10µF	3x22µF
3.3V	69.8KΩ	22.1KΩ	3.3µH	10.5KΩ	2.7nF	2x10µF	3x22µF
5.0V	115KΩ	22.1KΩ	3.6µH	15.8KΩ	2.7nF	2x10µF	3x22µF
12V	309KΩ	22.1KΩ	10µH	37.4KΩ	2.7nF	2x10µF	3x22µF

Table 1. Common Output Voltages

EVALUATION BOARD SCHEMATIC

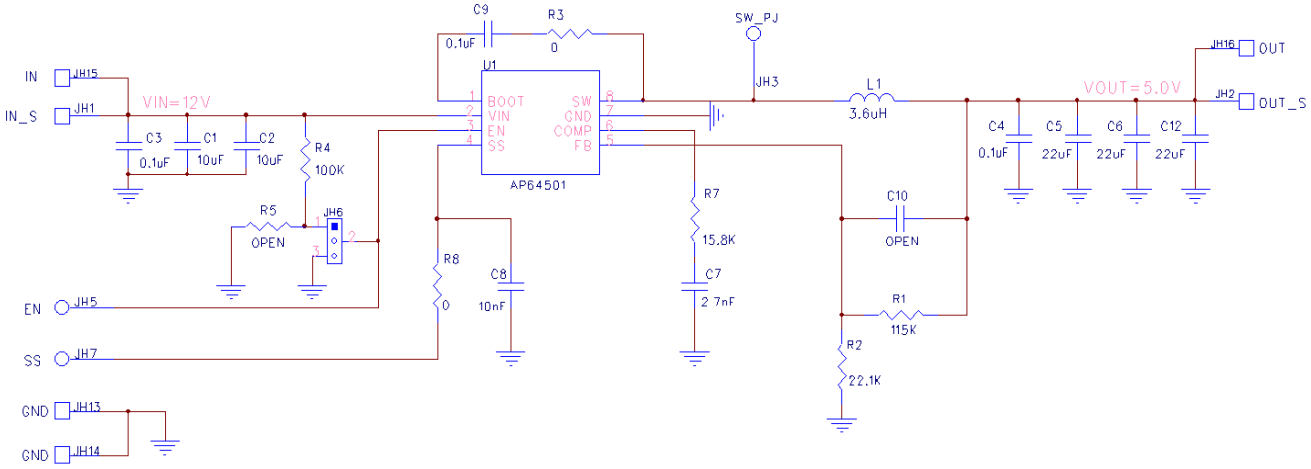


Figure 3. AP64501SP-EVM Schematic

PCB TOP LAYOUT

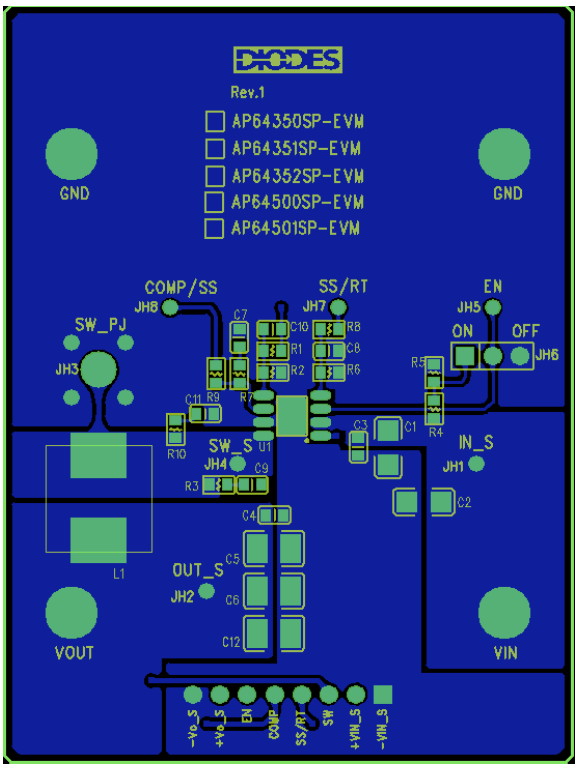


Figure 4. AP64501SP-EVM – Top Layer

PCB BOTTOM LAYOUT

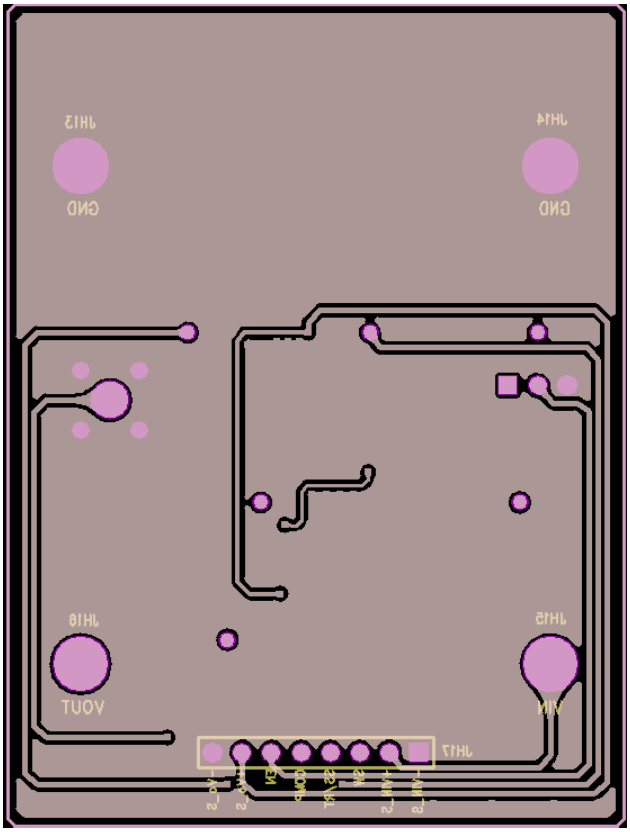


Figure 5. AP64501SP-EVM – Bottom Layer

BILL OF MATERIALS for AP64501SP-EVM for V_{OUT}=5V

Ref	Value	Description	Qty	Size	Vendor Name	Manufacturer PN
C1, C2	10µF	Ceramic Capacitor, 50V, X7R, 10%	2	1206	Samsung	CL31B106KBHNNNE
C3, C4	0.1µF	Ceramic Capacitor, 50V, X7R, 10%	2	0603	Wurth Electronics	885012206095
C5, C6, C12	22µF	Ceramic Capacitor, 16V, X7R	3	1210	Samsung	CL32B226KOJNNNE
C7	2.7nF	Ceramic Capacitor, 50V, X7R	1	0603	Murata	GRM1885C1H272JA01D
C8	10nF	Ceramic Capacitor, 25V, X7R	1	0603	Wurth Electronics	885012206065
C9	0.1µF	Ceramic Capacitor, 25V, X7R	1	0603	Wurth Electronics	885012206071
R1	115KΩ	RES SMD 1% 1/8W	1	0603	Panasonic	ERJ-3EKF1153V
R2	22.1KΩ	RES SMD 1% 1/8W	1	0603	Stackpole	RNCP0603FTD22K1
R3	0Ω	RES SMD 1% 1/10W	1	0603	Vishay	CRCW06030000Z0EAC
R4	100KΩ	RES SMD 1% 1/10W	1	0603	Vishay	CRCW0603100KFKEA
R7	15.8KΩ	RES SMD 1% 1/10W	1	0603	Bourns Inc	CR0603-FX-1582ELF
R8	0Ω	RES SMD 1% 1/10W	1	0603	Vishay	CRCW06030000Z0EAC
L1	3.6µH	DCR=12.2mΩ, Ir=8.2A	1	10.2x10.2x 4.5mm	Wurth Electronics	7447797360
JH6		PCB Header, 40 POS	1	1X3	3M	2340-611TG
JH13, JH14, JH15, JH16	1598	Terminal Turret Triple 0.094" L (Test Points)	4	Through-Hole	Keystone Electronics	1598-2
U1	AP64501	Sync DC/DC Converter	1	SO-8EP	Diodes Inc	AP64501SP

TYPICAL PERFORMANCE CHARACTERISTICS

Figure 6. Efficiency vs Output Current

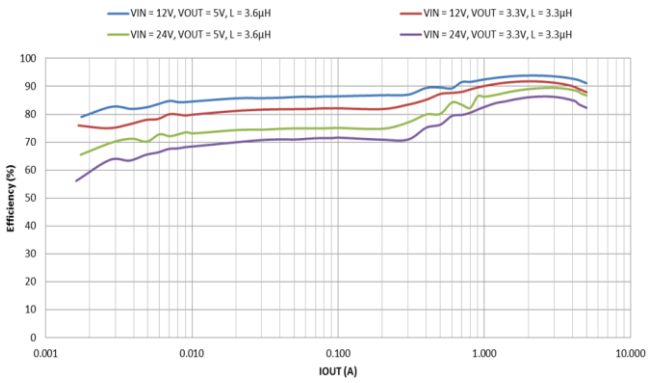


Figure 7. Load Transient, 3A to 5A

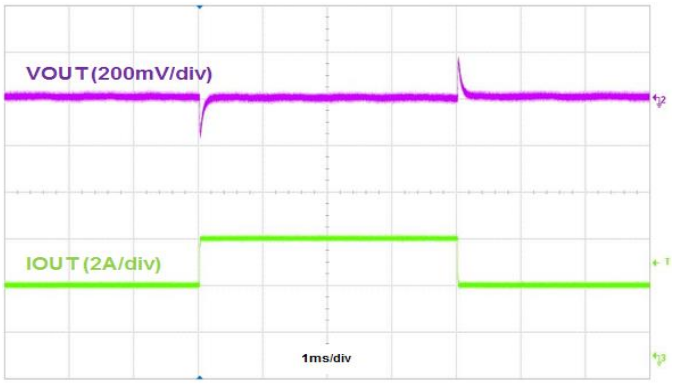


Figure 8. Output Voltage Ripple, IOUT=5A

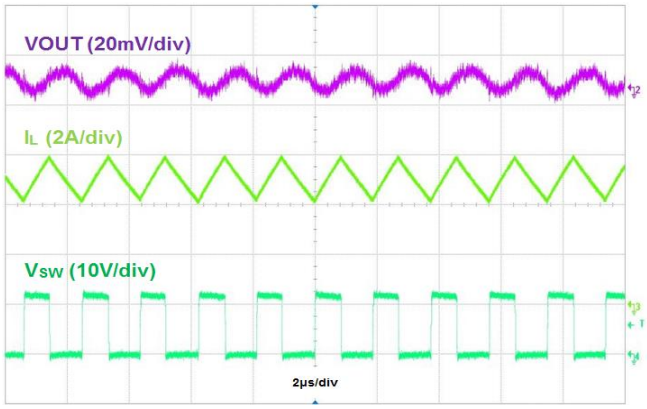
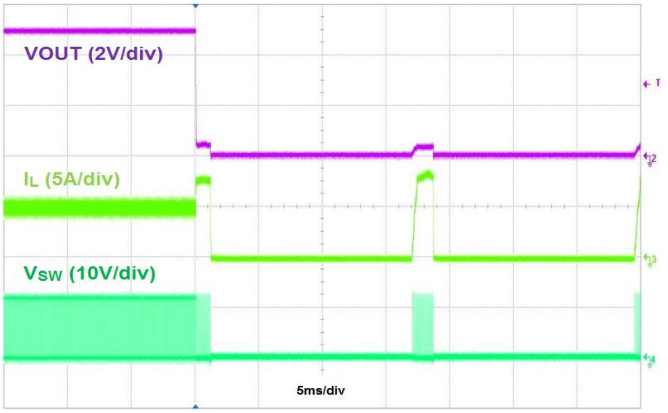


Figure 9. Output Short Protection, IOUT=5A



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